

TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (U-MOSVI-H)

# **TPCA8049-H**

Switching Regulator Applications Motor Drive Applications DC-DC Converter Applications

- Small footprint due to a small and thin package
- High-speed switching
- Small gate charge: Q<sub>SW</sub> = 13 nC (typ.)
- Low drain-source ON-resistance:  $R_{DS(ON)} = 6.6 \text{ m}\Omega$  (typ.)
- High forward transfer admittance:  $|Y_{fs}| = 88 \text{ S}$  (typ.)
- Low leakage current:  $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 60 \ V)$
- Enhancement mode:  $V_{th}$  = 1.3 to 2.3 V ( $V_{DS}$  = 10 V,  $I_D$  = 0.5 mA)

#### Absolute Maximum Ratings (Ta = 25°C)

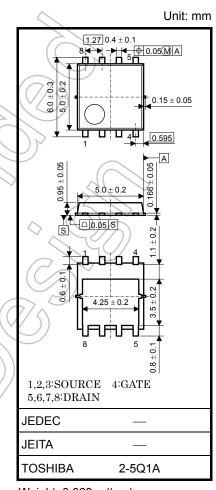
Characteristic		Symbol	Rating	Unit
Drain-source voltage		V <sub>DSS</sub>	60	V
Drain-gate voltage ( $R_{GS} = 20 \text{ k}\Omega$ )		V <sub>DGR</sub>	60	Y
Gate-source voltage		V <sub>GSS</sub>	±20	(v)
Drain current	DC (Note 1)	ID	28	A
Drain current	Pulsed (Note 1)	-IDP	84	
Drain power dissipation (Tc = 25°C)		PD	45	W
Drain power dissipation (t = 10 s) (Note 2a)		PD	2.8	W
Drain power dissipation $(t = 10 s)$ (Note 2b)		PD	1.6	w
Single-pulse avalanche energy (Note 3)		Eas	57	mJ
Avalanche current		I <sub>AR</sub>	28	А
Repetitive avalanche energy (Tc = 25°C) (Note 4)		E <sub>AR</sub>	2.85	mJ
Channel temperature		Tch	150	°C
Storage temperature range		Tstg	-55 to 150	°C

Note: For Notes 1 to 4, refer to the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e.

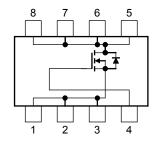
operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.



Weight: 0.069 g (typ.)

#### **Circuit Configuration**



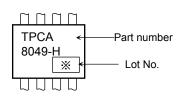
Start of commercial production 2008-10

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#### **Thermal Characteristics**

Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case (Tc = 25°C)	R <sub>th (ch-c)</sub>	2.78	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2a)	R <sub>th (ch-a)</sub>	44.6	°C/W
Thermal resistance, channel to ambient $(t = 10 \text{ s})$ (Note 2b)	R <sub>th (ch-a)</sub>	78.1	°C/W

#### Marking (Note 5)

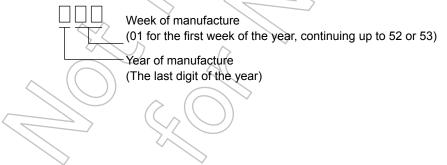


- Note 1: Ensure that the channel temperature does not exceed 150°C.
- Note 2: (a) Device mounted on a glass-epoxy board (a)



(b) Device mounted on a glass-epoxy board (b)

- Note 3:  $V_{DD} = 24 \text{ V}, \text{ T}_{ch} = 25^{\circ}\text{C}$  (initial), L = 100  $\mu$ H, R<sub>G</sub> = 25  $\Omega$ , I<sub>AR</sub> = 28 A
- Note 4: Repetitive rating: pulse width limited by maximum channel temperature
- Note 5: \* Weekly code: (Three digits)



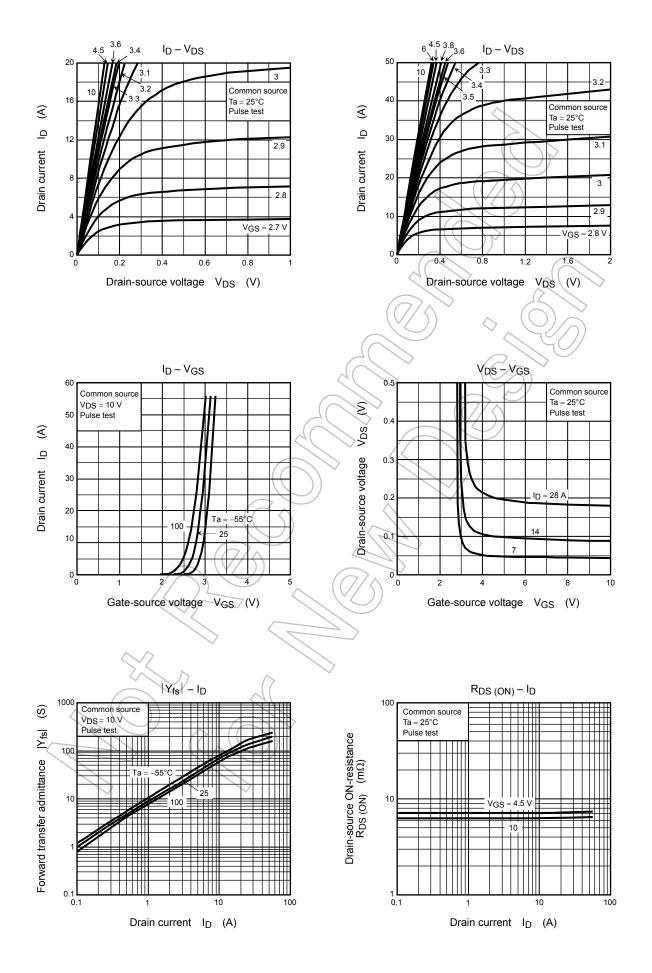
**Electrical Characteristics (Ta = 25°C)** 

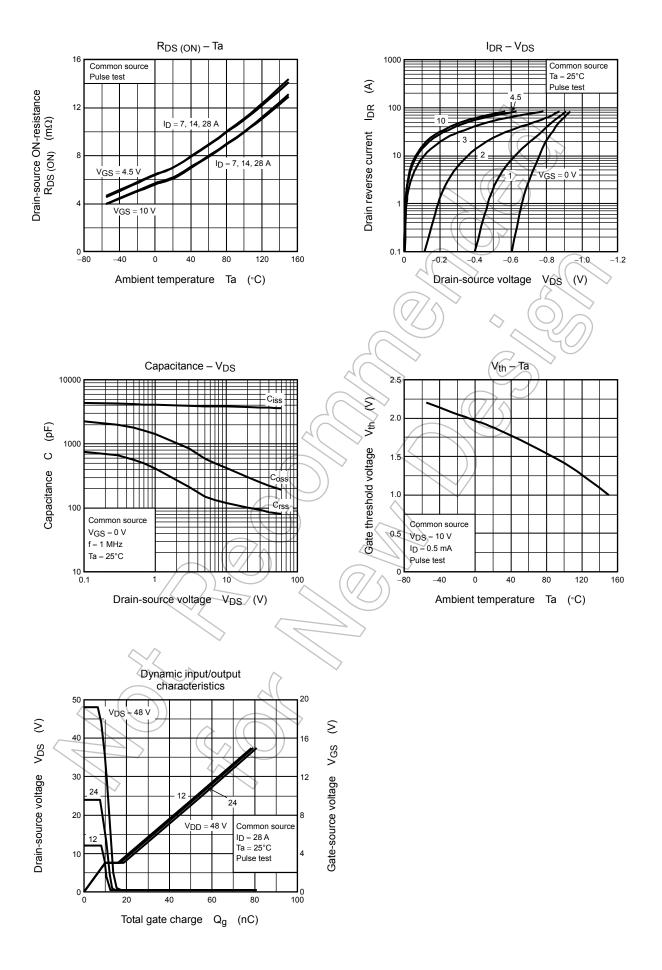
Ch	aracteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rent	I <sub>GSS</sub>	$V_{GS}=\pm 20~V,~V_{DS}=0~V$	_	_	±100	nA
Drain cutoff curre	ent	I <sub>DSS</sub>	$V_{DS} = 60 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	_	_	10	μA
Drain-source breakdown voltage		V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	60	_	_	v
		V (BR) DSX	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	45	1	_	v
Gate threshold ve	oltage	V <sub>th</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 0.5 \text{ mA}$	1.3	)/	2.3	V
Drain-source ON-resistance		R <sub>DS (ON)</sub>	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 14 \text{ A}$		7.4	11.2	mΩ
			V <sub>GS</sub> = 10 V, I <sub>D</sub> = 14 A	Ĥ	6.6	10.4	
Forward transfer	admittance	Y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 14 A	44	88	_	S
Input capacitance		C <sub>iss</sub>			3545	4610	
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	_	130	190	pF
Output capacitance		C <sub>oss</sub>		_	420	$\searrow$	
Gate resistance		rg	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	-6	1.0	1.5	Ω
Switching time	Rise time	tr	$V_{GS} = 14 \text{ A}$ $V_{GS} = 14 \text{ A}$ $V_{OV} $	K	2,9	) _	
	Turn-on time	t <sub>on</sub>		$\overline{\mathcal{A}}$	12	_	20
	Fall time	t <sub>f</sub>			5.6	_	ns
	Turn-off time	toff	$V_{DD} \approx 30 V$ Duty $\leq 1\%$ , t <sub>w</sub> = 10 µs	_	46	_	
Total gate charge (gate-source plus gate-drain)		Qg	$V_{DD} \approx 48 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 28 \text{ A}$		55		
			$V_{DD} \approx 48 \text{ V}, \text{ V}_{GS} = 5 \text{ V}, \text{ I}_{D} = 28 \text{ A}$		29		
Gate-source cha	rge 1	Q <sub>gs1</sub>		_	10		nC
Gate-drain ("Miller") charge		Qgd	$V_{DD} \approx 48 \text{ V}, \text{V}_{GS} = 10 \text{ V}, \text{I}_{D} = 28 \text{ A}$		8.5		
Gate switch charge		Q <sub>SW</sub>		_	13	_	

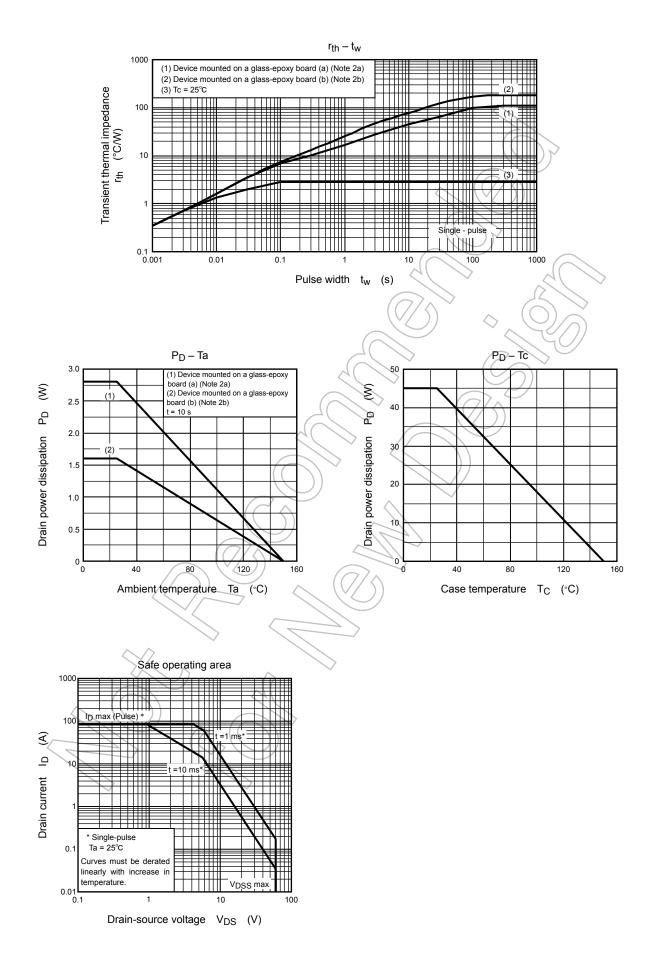
### Source-Drain Ratings and Characteristics ( $Ta = 25^{\circ}C$ )

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Drain reverse current Pulse (Note 1)	I <sub>DRP</sub>	> -		_	84	А
Forward voltage (diode)	VDSF	I <sub>DR</sub> = 28 A, V <sub>GS</sub> = 0 V			-1.2	V

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